

## NCE N-Channel Enhancement Mode Power MOSFET

## Description

The NCE0160G uses advanced trench technology and design to provide excellent  $R_{DS(ON)}$  with low gate charge. This device is suitable for use in PWM, load switching and general purpose applications.

## **General Features**

V<sub>DS</sub> = 100V,I<sub>D</sub> =60A
R<sub>DS(ON)</sub> <16mΩ @ V<sub>GS</sub>=12.6V

- Special designed for convertors and power controls
- High density cell design for ultra low Rdson
- Fully characterized Avalanche voltage and current
- Good stability and uniformity with high E<sub>AS</sub>
- Excellent package for good heat dissipation

## Application

- Power switching application
- Hard switched and high frequency circuits
- Uninterruptible power supply

#### 100% UIS TESTED!

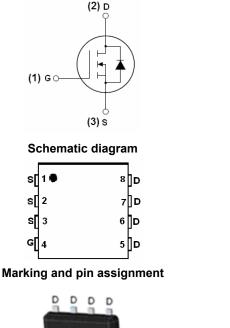
#### 100% ΔVds TESTED!

#### Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
NCE0160G	NCE0160G	DFN5X6-8L	-	-	-

#### Absolute Maximum Ratings (T<sub>C</sub>=25<sup>°</sup>C unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	Vds	100	V
Gate-Source Voltage	Vgs	±20	V
Drain Current-Continuous	I <sub>D</sub>	60	А
Drain Current-Continuous(T <sub>C</sub> =70°C)	I <sub>D</sub> (70℃)	50	А
Pulsed Drain Current	I <sub>DM</sub>	80	А
Maximum Power Dissipation	PD	105	W
Derating factor		0.70	W/℃
Single pulse avalanche energy (Note 5)	E <sub>AS</sub>	550	mJ
Operating Junction and Storage Temperature Range	T <sub>J</sub> ,T <sub>STG</sub>	-55 To 175	°C





DFN5X6-8L top view



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## **Thermal Characteristic**

Thermal Resistance, Junction-to- Case (Note 2)	R <sub>θJc</sub>	1.43	°C/W	
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## Electrical Characteristics (T<sub>C</sub>=25°C unless otherwise noted)

Symbol	Condition	Min	Тур	Max	Unit
	·				
BV <sub>DSS</sub>	V <sub>GS</sub> =0V I <sub>D</sub> =250μA 10		110	-	V
I <sub>DSS</sub>	V <sub>DS</sub> =100V,V <sub>GS</sub> =0V	-	-	1	μA
I <sub>GSS</sub>	V <sub>GS</sub> =±20V,V <sub>DS</sub> =0V	-	-	±100	nA
		•			
V <sub>GS(th)</sub>	V <sub>DS</sub> =V <sub>GS</sub> ,I <sub>D</sub> =250µA	2.5	3.7	4.5	V
R <sub>DS(ON)</sub>	V <sub>GS</sub> =10V, I <sub>D</sub> =30A	-	12.6	16	mΩ
<b>g</b> fs	V <sub>DS</sub> =15V,I <sub>D</sub> =10A	-	30	-	S
		•			
Clss	)/ <u>50)///</u> 0)/	-	2850	-	PF
C <sub>oss</sub>		-	220	-	PF
C <sub>rss</sub>	F=1.0MHZ	-	90	-	PF
		•			
t <sub>d(on)</sub>		-	17	-	nS
tr	$V_{DD}$ =30V,I <sub>D</sub> =5A,R <sub>L</sub> =10 $\Omega$	-	10	-	nS
t <sub>d(off)</sub>	$V_{GS}$ =10V, $R_{G}$ =1 $\Omega$	-	26	-	nS
t <sub>f</sub>		-	10	-	nS
Qg	N/ 50)/1 40A	-	47	-	nC
Q <sub>gs</sub>		-	13		nC
Q <sub>gd</sub>	V <sub>GS</sub> =10V	-	12.5	-	nC
		•			
V <sub>SD</sub>	V <sub>GS</sub> =0V,I <sub>S</sub> =4A	-	-	1.2	V
I <sub>S</sub>		-	-	60	А
t <sub>rr</sub>	TJ = 25°C, IF = 10A	-	-	60	nS
Qrr	di/dt = 100A/µs <sup>(Note3)</sup>	-	-	200	nC
t <sub>on</sub>	Intrinsic turn-on time is negligible (turn-on is dominated by LS+LD)				
	BVDSS       IDSS       IDSS       IGSS       VGS(th)       RDS(ON)       GFS       Clss       Clss       Crss       Crss       td(on)       tr       d(off)       tf       Qg       Qgs       Qgd       VSD       Is       trr       Qrr		$\begin{tabular}{ c c c c c } \hline $V_{GS}$ & $V_{GS}=0V \ I_{D}=250\mu A$ & 100 \\ \hline $I_{DSS}$ & $V_{DS}=100V, $V_{GS}=0V$ & -$ \\ \hline $I_{GSS}$ & $V_{GS}=\pm 20V, $V_{DS}=0V$ & -$ \\ \hline $I_{GSS}$ & $V_{GS}=\pm 20V, $V_{DS}=0V$ & -$ \\ \hline $V_{GS(th)}$ & $V_{DS}=V_{GS}, $I_{D}=250\mu A$ & 2.5 \\ \hline $R_{DS(ON)}$ & $V_{GS}=10V, $I_{D}=30A$ & -$ \\ \hline $V_{DS}$ & $V_{DS}=15V, $I_{D}=10A$ & -$ \\ \hline $V_{C}$ & $V_{DS}=50V, $V_{GS}=0V,$ \\ \hline $C_{rss}$ & $V_{DS}=50V, $V_{GS}=0V,$ \\ \hline $C_{rss}$ & $V_{DS}=50V, $V_{GS}=0V,$ \\ \hline $C_{rss}$ & $V_{DS}=50V, $I_{D}=10A$ & -$ \\ \hline $V_{C}$ & $V_{DD}=30V, $I_{D}=5A, $R_{L}=10\Omega$ & -$ \\ \hline $V_{C}$ & $V_{DS}=10V, $R_{G}=1\Omega$ & -$ \\ \hline $V_{C}$ & $V_{DS}=50V, $I_{D}=10A$ & -$ \\ \hline $V_{C}$ & $V_{CS}=10V$ & $-$ \\ \hline $V_{SD}$ & $V_{GS}=0V, $I_{S}=4A$ & -$ \\ \hline $V_{SD}$ & $V_{GS}=0V, $I_{S}=4A$ & -$ \\ \hline $I_{S}$ & $-$ \\ \hline $V_{TT}$ & $TJ=25^{\circ}C, $IF=10A$ & -$ \\ \hline $Q_{TT}$ & $di/dt=100A/\mu s^{(Note3)}$ & -$ \\ \hline $V_{SD}$ & $V_{CS}=0V, $I_{S}=10V$ & $-$ \\ \hline $V_{SD}$ & $V_{CS}=0V, $I_{S}=10A$ & -$ \\ \hline $V_{SD}$ & $V_{CS}=0V, $I_{S}=10A$ & -$ \\ \hline $V_{SD}$ & $V_{CS}=0V, $I_{S}=10A$ & -$ \\ \hline $V_{SD}$ & $V_{CS}=0V, $I_{S}=4A$ & -$ \\ \hline $I_{S}$ & $-$ \\ \hline $V_{TT}$ & $TJ=25^{\circ}C, $IF=10A$ & -$ \\ \hline $V_{SD}$ & $V_{CS}=0V, $I_{S}=10A$ & -$ \\ \hline $V_{SD}$ & $V_{CS}=0V, $I_{S}=10A$ & -$ \\ \hline $V_{SD}$ & $V_{CS}=0V, $I_{S}=10A$ & -$ \\ \hline $V_{SD}$ & $V_{CS}=0V, $I_{S}=4A$ & -$ \\ \hline $V_{SD}$ & $V_{CS}=0V, $I_{S}=4A$ & -$ \\ \hline $V_{SD}$ & $V_{CS}=0V, $I_{S}=4A$ & -$ \\ \hline $V_{SD}$ & $V_{CS}=0V, $I_{S}=10A$ & -$ \\ \hline $V_{SD}$ & $V_{SD}$ &$	$ \begin{array}{ c c c c c c c c c c c c c c c c c c c$	$ \begin{array}{ c c c c c c } \hline BV_{DSS} & V_{GS} = 0V \ I_D = 250 \mu A & 100 & 110 & - \\ \hline I_{DSS} & V_{DS} = 100V, V_{GS} = 0V & - & - & 1 \\ \hline I_{GSS} & V_{GS} = \pm 20V, V_{DS} = 0V & - & - & \pm 100 \\ \hline \\ \hline V_{GS(th)} & V_{DS} = V_{GS}, I_D = 250 \mu A & 2.5 & 3.7 & 4.5 \\ \hline \\ \hline R_{DS(ON)} & V_{GS} = 10V, \ I_D = 30A & - & 12.6 & 16 \\ \hline \\ g_{FS} & V_{DS} = 15V, I_D = 10A & - & 30 & - \\ \hline \\$

Notes:

- 1. Repetitive Rating: Pulse width limited by maximum junction temperature.
- 2. Surface Mounted on FR4 Board, t ≤ 10 sec.
- **3.** Pulse Test: Pulse Width  $\leq$  300µs, Duty Cycle  $\leq$  2%.
- 4. Guaranteed by design, not subject to production
- **5.** EAS condition: Tj=25  $^{\circ}$ C,V<sub>DD</sub>=50V,V<sub>G</sub>=10V,L=0.5mH,Rg=25 $\Omega$

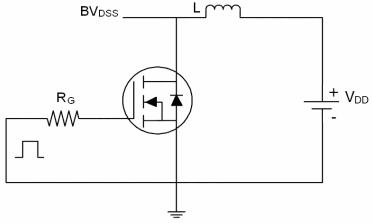


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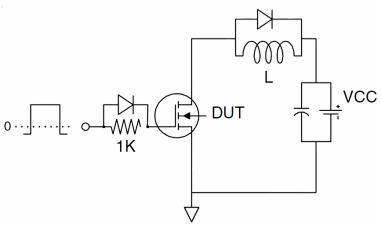




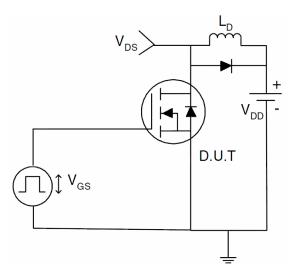
## Test Circuit 1) E<sub>AS</sub> test Circuit



## 2) Gate charge test Circuit

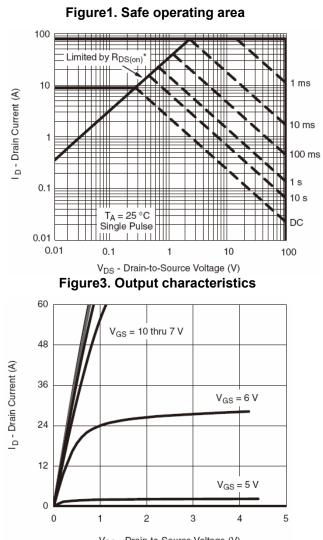


## 3) Switch Time Test Circuit

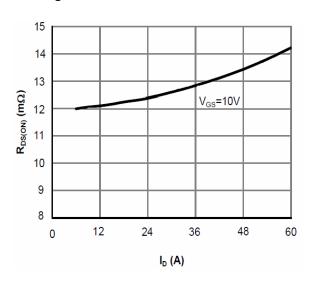


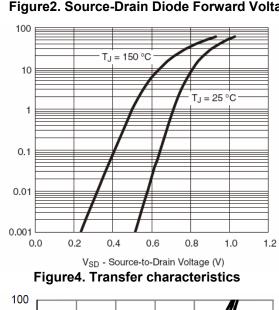


## Typical Electrical and Thermal Characteristics (Curves)



V<sub>DS</sub> - Drain-to-Source Voltage (V) Figure5. Static drain-source on resistance





Is - Source Current (A)

## Figure2. Source-Drain Diode Forward Voltage

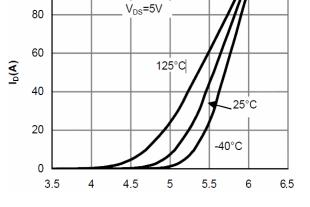
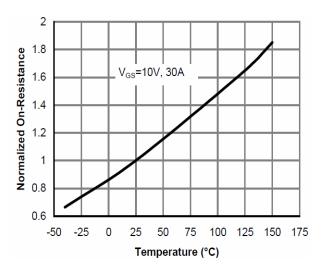


Figure6. R<sub>DS(ON)</sub> vs Junction Temperature





V<sub>GS</sub> - Gate-to-Source Voltage (V)

Figure7. BV<sub>DSS</sub> vs Junction Temperature

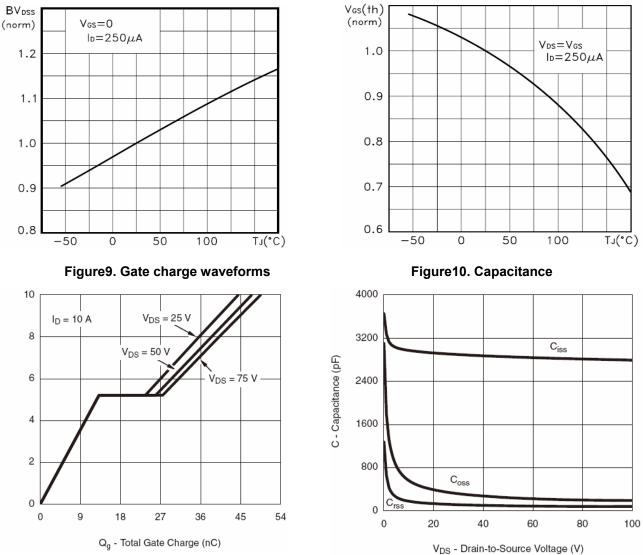


Figure11. Normalized Maximum Transient Thermal Impedance

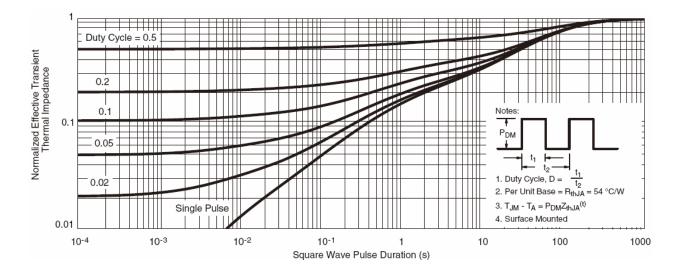


Figure8. V<sub>GS(th)</sub> vs Junction Temperature

**Pb Free Product** 

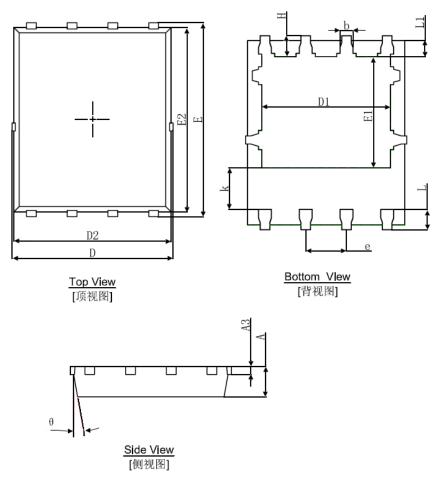
**NCE0160G** 





# NCE0160G

## DFN5X6-8L Package Information



Symbol	Dimensions	In Millimeters	Dimensions In Inches		
	Min.	Max.	Min.	Max.	
А	0.900	1.000	0.035	0.039	
A3	0.254	IREF.	0.010	REF.	
D	4.944	5.096	0.195	0.201	
E	5.974	6.126	0.235	0.241	
D1	3.910	4.110	0.154	0.162	
E1	3.375	3.575	0.133	0.141	
D2	4.824	4.976	0.190	0.196	
E2	5.674	5.826	0.223	0.229	
К	1.190	1.390	0.047	0.055	
b	0.035	0.450	0.014	0.018	
e	1.270(TYP.)		0.050(TYP.)		
L	0.559	0.711	0.022	0.028	
L1	0.424	0.576	0.017	0.023	
Н	0.574	0.726	0.023	0.029	
θ	8°	12°	8°	12°	







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